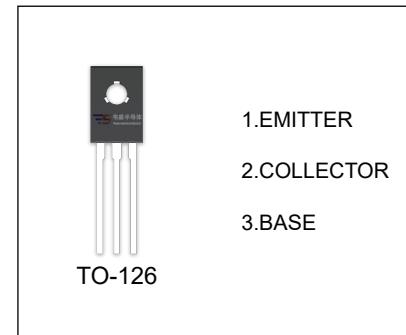


BD433 / BD435 / BD437 TRANSISTOR (NPN)

FEATURES

- Amplifier and Switching Applications
- Complement To BD434, BD436 And BD438



ORDERING INFORMATION

Part Number	Package	Packing Method	Pack Quantity
BD433	TO-126	Bulk	200pcs/Bag
BD435	TO-126	Bulk	200pcs/Bag
BD437	TO-126	Bulk	200pcs/Bag
BD433-TU	TO-126	Tube	60pcs/Tube
BD435-TU	TO-126	Tube	60pcs/Tube
BD437-TU	TO-126	Tube	60pcs/Tube

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	BD433 BD435 BD437	V
		22 32 45	
V_{CEO}	Collector-Emitter Voltage	BD433 BD435 BD437	V
		22 32 45	
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current –Continuous	4	A
P_c	Collector Power Dissipation	1.25	W
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55-150	°C

T_a=25 °C unless otherwise specified

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =100μA,I _E =0 BD433 BD435 BD437	22 32 45			V
Collector-emitter breakdown voltage	V _{CE(SUS)} ⁽¹⁾	I _C =100mA,I _B =0 BD433 BD435 BD437	22 32 45			V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =100μA,I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} =22V,I _E =0 V _{CB} =32V,I _E =0 V _{CB} =45V,I _E =0 BD433 BD435 BD437			100	μA
Collector cut-off current	I _{CEO}	V _{CE} =22V,I _E =0 V _{CE} =32V,I _E =0 V _{CE} =45V,I _E =0 BD433 BD435 BD437			100	μA
Emitter cut-off current	I _{EBO}	V _{EB} =5V,I _E =0			1	mA
DC current gain	h _{FE(1)} ⁽¹⁾	V _{CE} =1V,I _C =500mA	85		375	
	h _{FE(2)} ⁽¹⁾	V _{CE} =5V,I _C =10mA BD433/BD435 BD437	40 30			
	h _{FE(3)} ⁽¹⁾	V _{CE} =1V,I _C =2A BD433/BD435 BD437	50 40			
Collector-emitter saturation voltage	V _{CE(sat)} ⁽¹⁾	I _C =2A,I _B =0.2A BD433/BD435 BD437			0.5 0.6	V
Base-emitter voltage	V _{BE} ⁽¹⁾	V _{CE} =1V,I _C =2A BD433/BD435 BD437			1.1 1.2	V
Transition frequency	f _T	V _{CE} =1V,I _C =250mA	3			MHz

⁽¹⁾Pulse test.